1A Charge+ 2.7A Synchronous Boost PMIC

General Description

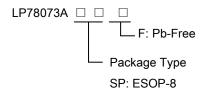
The LP78073A is a PMIC, which has 1ch Charger and 1ch Synchronous Boost Converter with ESOP-8 package.

Its charger is a complete constant-current constant voltage linear charger for single cell lithium-ion batteries. Furthermore, the LP78073A is specifically designed to work within USB power specifications. No external sense resistor is needed, and no blocking diode is required due to the internal MOSFET architecture. Thermal feedback regulates the charge current to limit the die temperature during high power operation or high ambient temperature. The charge voltage is fixed at 4.2V, and the charge current can be ISET rammed externally with a single resistor. The charger automatically terminates the charge cycle when the charge current drops to 1/10th the ISET rammed value after the final float voltage is reached. When the input supply (wall adapter or USB supply) is removed, the LP78073A automatically enters a low current state, dropping the battery drain current to less than 8µA.

Other features include charge current monitor, under voltage lockout, automatic recharge and a status pin to indicate charge termination and the presence of an input voltage.

Boost converter is Synchronous current mode boost DC-DC converter. Its PWM circuitry with built-in 2.7A Current power MOSFET makes this converter highly power efficiently. Selectable high switching frequency allows faster loop response and easy filtering with a low noise output. The non-inverting input and its error amplifier is connected to an internal 800mV precision reference voltage.

Order Information



Features

- Charger:
 - Programmable Charge Current Up to 1000mA
 - No MOSFET, Sense Resistor or Blocking Diode Required
 - Constant-Current/Constant-Voltage Operation with Thermal Regulation to Maximize Charge Rate Without Risk of Overheating
 - Charges Single Cell Li-Ion Batteries Directly from USB Port
 - 8µA Supply Current in Shutdown
 - Drainage Charge Current Thermal Regulation Status
 Outputs for LED or System Interface
- Boost:
 - 5V/1.2A Output Current @ Vin=3.3V
 - 1MHz fixed frequency switching
 - High Switch On Current: 2.7A
 - Low RDS(ON) Integrated Power Mosfet
 - Efficiency is 95%
 - Built-in OTP, OCP, Soft-Star
- ◆ Consumption Available in ESOP-8 Package
- RoHS Compliant and 100% Lead (Pb)-Free

Applications

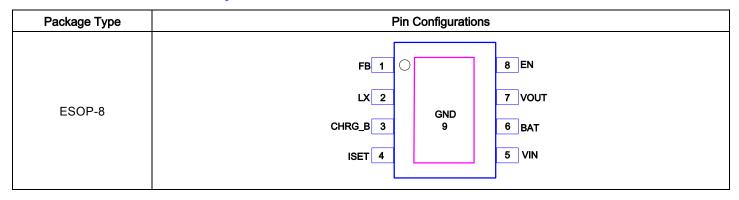
- ♦ MID/Pad
- ♦ Power Bank
- ♦ Smart Phone
- ♦ Bluetooth Applications

Marking Information

Device	Marking	Package	Shipping
LP78073ASPF		SP:ESOP-8	2.5K/REEL

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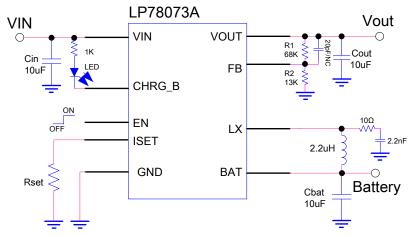
Functional Pin Description



Pin Description

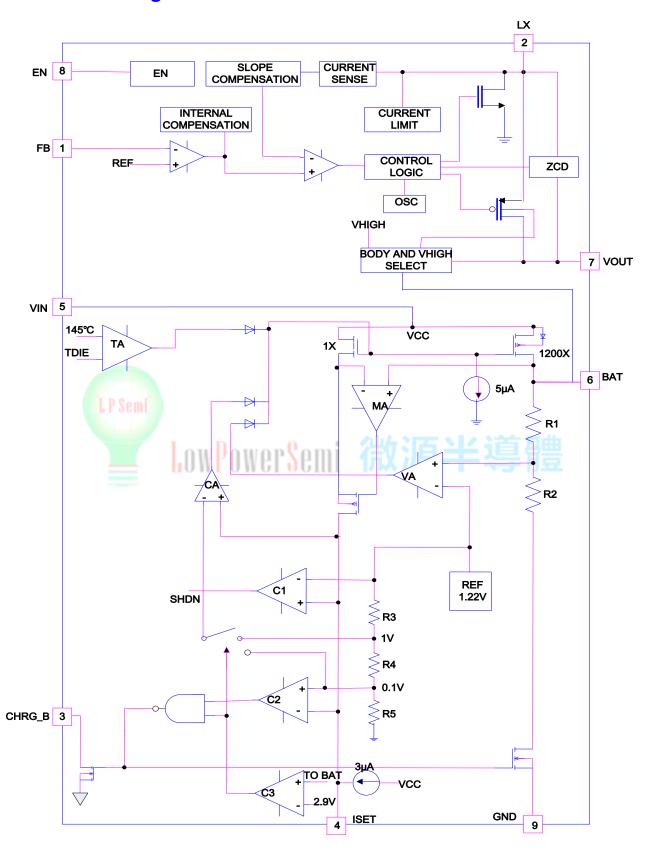
PIN	NAME	DESCRIPTION		
1	FB	Boost Feedback pin. The pin voltage is 0.8V.		
2	LX	Boost Output switching node. SW is the drain of the internal low-side N-Channel MOSFET and high-side		
		P-Channel MOSFET. Connect the inductor to SW to Complete the step-up converter.		
3	CUDC B	Open-Drain Charge Status Output. When the battery is charging, the STAT pin is pulled low by an internal		
3	CHRG_B	N-channel MOSFET. When the charge cycle is completed, the pin is pulled High.		
	ISET	Charge Current Program, Charge Current Monitor and Shutdown Pin. The charge current is programmed by		
		connecting a 1% resistor(R _{PROG})to ground. When charging in constant-current mode, this pin servos to 2V. In all		
4		modes, the voltage on this pin can be used to measure the charge current using the following formula.LP78073A:		
		Iset=1000/R _{PROG} .		
5	Vin	VIN is the input power source. Connect to a wall adapter.		
6	BAT	BAT is the connection to the battery. A 10µF capacitor is needed at least.		
7	VOUT	Output voltage pin.		
8	EN	Boost enable pin. Active High.		
9	GND	Ground Pin.		

Application Circuit



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Function Block Diagram



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Absolute Maximum Ratings Note 1

\diamond	Input and LX Voltage to GND	0.3V to 6.5V
	Output Voltage to GND	0.3V to 6V
	Other Pin to GND	0.3V to 6V
\diamondsuit	Maximum Junction Temperature	150°C
\diamondsuit	BAT Short-Circuit Duration	Continuous
	Operating Ambient Temperature Range (TA)	40°C to 85°C
	Maximum Soldering Temperature (at leads, 10 sec)	260°C

Note 1. Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Thermal Information

\diamond	Maximum Power Dissipation (ESOP-8, PD,TA=25°C) 2W	

♦ Thermal Resistance (ESOP-8, JA) ------ 50°C/W

ESD Susceptibility

♦ HBM(Human Body Mode) ------ 2KV

≻ MM(Machine Mode) ------ 200V

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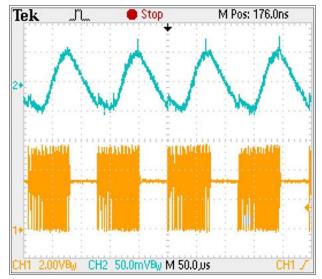
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Electrical Characteristics

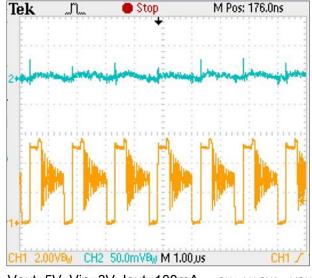
SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNITS	
Charge					•		
VIN	Adapter/USB Voltage Range		4	5	6	V	
		Charge Mode, RISET = 10k		300	2000		
lin	Innuit County Course	Standby Mode (Charge Terminated)		200	500	uA	
	Input Supply Current	Shutdown Mode (RISET Not Connected, VIN		25	50		
		< VBAT, or VIN < VUV)		25	30		
VFLOAT	Regulated Output (Float) Voltage	0°C ≤ TA ≤ 85°C, IBAT = 40mA	4.158	4.2	4.242	V	
		RISET = 1k, Current Mode		1000		mA	
		RISET = 2k, Current Mode		500		ША	
IBAT	BAT Pin Current	Standby Mode, VBAT = 4.2V,EN=High		-200	-260		
		Shutdown Mode (RISET Not Connected)	0	±5	±8	uA	
		Sleep Mode, VIN = 0V ,EN=0V		±5	±8		
ITRIKL	Trickle Charge Current	VBAT < VTRIKL, RISET = 2k		50		mA	
VTRIKL	Trickle Charge Threshold Voltage	RISET = 10k, VBAT Rising	2.8	2.9	3.0	V	
VTRHYS	Trickle Charge Hysteresis Voltage	RISET = 10k		120		mV	
VUV	VIN Under voltage Lockout Threshold	From VIN Low to High		3.9		V	
VUVHYS	VIN Under voltage Lockout Hysteresis		150	200	300	mV	
		VIN from Low to High	70	100	140	mV	
VASD	VIN – VBAT Lockout Threshold Voltage	VIN from High to Low	5	30	50	mV	
		RISET = 10k		10		%IBAT	
ITERM	C/10 Termination Current Threshold	RISET = 2k	46	10		%IBAT	
VISET	ISET Pin Voltage	RISET = 10k, Current Mode	-	2		V	
VSTAT	STAT Pin Output Low Voltage	ISTAT = 5mA		0.35	0.6	V	
ΔVRESTAT	Recharge Battery Threshold Voltage	VFLOAT - VRESTAT	100	150	200	mV	
TLIM	Junction Temperature in Constant Temperature	ure Mode	l		150	°C	
RON	Power FET "ON" Resistance (Between VIN a	and BAT)			300	mΩ	
Boost(VBAT=3.5\	/, Vout=5V, TA=25°C)					-	
Vout	Output Voltage Range		2.5		5.4	V	
UVLO	UVLO		1.5		2.5	V	
Vfb	Feedback Voltage		784	800	816	mV	
Ifb	Feedback Input Current	VFB=0.8V		50		nA	
Fosc	Switching Frequency			1000		KHz	
Duty	Maximum Duty Cycle		80	90	95	%	
VENL	EN Input Low Voltage				0.4	V	
VENH	EN Input High Voltage		1.4			V	
lLimit	Low-side Current Limit		2.7	3		Α	
	High-side On Resistance	Vout=3.3V		110		mΩ	
Rds(on)	Low-side On Resistance			70		mΩ	

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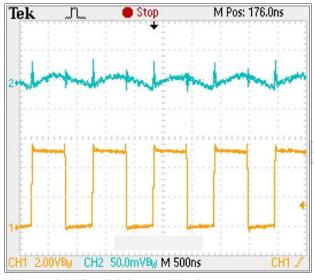
Typical Operating Characteristics



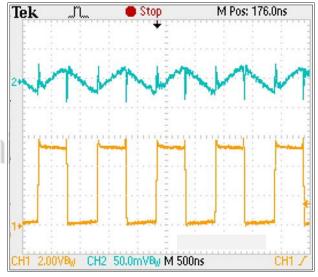
Vout=5V, Vin=3V, Iout=2mA, CH1=LX,CH2=AVOUT



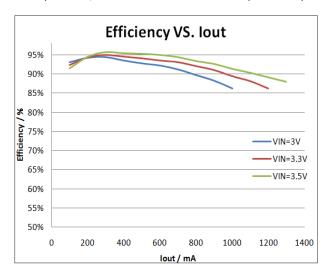
Vout=5V, Vin=3V, lout=100mA , CH1=LX,CH2= \triangle VOUT



Vout=5V, Vin=3V, Iout=500mA, CH1=LX,CH2=AVOUT



Vout=5V, Vin=3V, Iout=1A, CH1=LX,CH2=AVOUT



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Charge Characteristics

TYPICAL CHARACTERISTICS

DROPOUT VOLTAGE JUNCTION TEMPERATURE 850 IO(OUT) = 1000 mA 750 650 IO(OUT) = 750 mADropout Voltage - mV 550 450 IO(OUT) = 500 mA350 250 IO(OUT) = 250 mA 150 50 -50 150 T_J – Junction Temperature – °C Figure 1

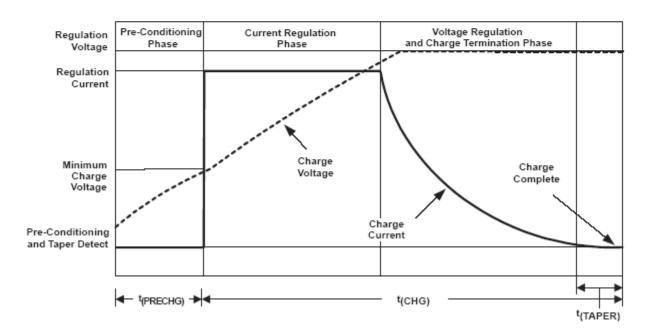


Figure 2. Typical Charging Profile

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Application Information

The LP78073A is a single cell lithium-ion battery charger using a constant-current/constant-voltage algorithm. It can deliver up to 1000mA of charge current (using a good thermal PCB layout) with a final float voltage accuracy of ±1%. The LP78073A includes an internal P-channel power MOSFET and thermal regulation circuitry. No blocking diode or external current sense resistor is required; thus, the basic charger circuit requires only two external components. Furthermore, the LP78073A is capable of operating from a USB power source.

For boost function, LP78073Awill stay in PSM(Pulse Skipping Modulation) mode when there is a light load. This could reduce unnecessary dissipation to promote efficiency. When the load grow to a certain level the boost circuit would turn to PWM mode gradually.

Normal Charge Cycle

A charge cycle begins when the voltage at the VIN pin rises above the UVLO threshold level and a 1% ISET ram resistor is connected from the ISET pin to ground or when a battery is connected to the charger output. If the BAT pin is less than 2.9V, the charger enters trickle charge mode. In this mode, the LP78073A supplies approximately 1/10 the ISET rammed charge current to bring the battery voltage up to a safe level for full current charging.

When the BAT pin voltage rises above 2.9V, the charger enters constant-current mode, where the ISET rammed charge current is supplied to the battery. When the BAT pin approaches the final float voltage (4.2V), the LP78073A enters constant-voltage mode and the charge current begins to decrease. When the charge current drops to 1/10 of the ISET rammed value, the charge cycle ends.

ISET ramming Charge Current

The charge current is ISET rammed using a single resistor from the ISET pin to ground. The battery charge current is 500 times the current out of the ISET pin. The ISET ram resistor and the charge current are calculated using the following equations:

LP78073A:

RSET=1000V/ICHG, ICHG=1000V/RSET

The charge current out of the BAT pin can be determined at any time by monitoring the ISET pin voltage using the following equation:

IBAT= VSET x 500/RSET

Note: Vset is 2Volts.

Charge Termination

When charging, transient loads on the BAT pin can cause the ISET pin to fall below 200mV for short periods of time before the DC charge current has dropped to 1/10th the ISET rammed value. The 1ms filter time (t_{TERM}) on the termination comparator ensures that transient loads of this nature do not result in premature charge cycle termination. Once the average charge current drops below 1/10th the ISET rammed value, the LP78073A terminates the charge cycle and ceases to provide any current through the BAT pin. In this state, all loads on the BAT pin must be supplied by the battery.

The LP78073A constantly monitors the BAT pin voltage in standby mode. If this voltage drops below the 4.05V recharge threshold (V_{RESTAT}), another charge cycle begins and current is once again supplied to the battery. To manually restart a charge cycle when in standby mode, the input voltage must be removed and reapplied, or the charger must be shut down and restarted using the ISET pin.

Charge Status Indicator (STAT)

The charge status output has two different states: strong pull-down (~10mA) and high impedance. The strong pull-down state indicates that the LP78073A is in a charge cycle. Once the charge cycle has terminated, the pin state is determined by under voltage lockout conditions. High impedance indicates that the LP78073A is in under voltage lockout mode: either VIN is less than 100mV above the BAT pin voltage or insufficient voltage is applied to the VIN pin.

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Thermal Limiting

An internal thermal feedback loop reduces the ISET rammed charge current if the die temperature attempts to rise above a preset value of approximately 150°C. This feature protects the LP78073A from excessive temperature and allows the user to push the limits of the power handling capability of a given circuit board without risk of damaging the LP78073A. The charge current can be set according to typical (not worst-case) ambient temperature with the assurance that the charger will automatically reduce the current in worst-case conditions. Automatic Recharge

Once the charge cycle is terminated, the LP78073A continuously monitors the voltage on the BAT pin using a comparator with a 2ms filter time ($t_{RECHARGE}$). A charge cycle restarts when the battery voltage falls below 4.05V (which corresponds to approximately 80% to 90% battery capacity). This ensures that the battery is kept at or near a fully charged condition and eliminates the need for periodic charge cycle initiations. STAT output enters a strong pull-down state during recharge cycles.

Boost Under voltage Lockout (UVLO)

An internal under voltage lockout circuit monitors the input voltage is 2.5V and keeps the charger in shutdown mode until VIN rises above the under voltage lockout threshold. The UVLO circuit has a built-in hysteresis of 500mV.Furthermore, to protect against reverse current in the power MOSFET, the UVLO circuit keeps the charger in shutdown mode if VIN falls

to within 30mV of the battery voltage. If the UVLO comparator is tripped, the charger will not come out of shutdown mode until VIN rises 100mV above the battery voltage.

BOOST Output voltage Setting

Set the output voltage by selecting the resistive voltage divider ratio. The voltage divider drops the output voltage to the 0.8V feedback voltage. Use a 100K resistor for R2 of the voltage divider. Determine the high-side resistor R1 by the equation:

 $Vout=(R1/R2+1) \times VFB$

Vout=(R1/R2+1) x 0.8V

Power Dissipation

The conditions that cause the LP78073A to reduce charge current through thermal feedback can be approximated by considering the power dissipated in the IC. Nearly all of this power dissipation is generated by the internal MOSFET—this is calculated to be approximately:

PD=(VIN-VBAT) • IBAT

where PD is the power dissipated, VIN is the input supply voltage, VBAT is the battery voltage and IBAT is the charge current. The approximate ambient temperature at which the thermal feedback begins to protect the IC is:

TA=150°C-PD0JA

TA=150°C-(VIN-VBAT) • IBAT • θJA

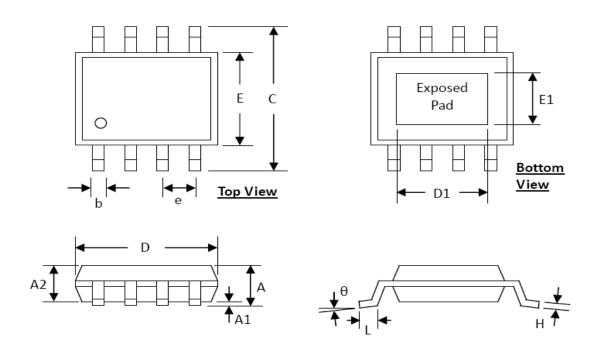
PCB Layout Considerations

For high frequency switching power supplies, the PCB layout is important step in system application design. In order to let IC achieve good regulation, high efficiency and stability, it is strongly recommended the power components(Inductor, input and output capacitor) should be placed as close as possible to chip. The set races should be wide and short. The feedback pin and then works of feedback and compensation should keep away from the power loops, and be shielded with a ground trace or plane to prevent noise coupling.

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Packaging Information

ESOP-8



SYMBOLS	DIMENSION (MM)		DIMENSION (INCH)		
STIVIBULS	MIN	MAX	MIN	MAX	
Α	1.30	1.70	0.051	0.067	
A1	0.00	0.15	0.000	0.006	
A2	1.25	1.52	0.049	0.060	
b	0.33	0.51	0.013	0.020	
С	5.80	6.20	0.228	0.244	
D	4.80	5.00	0.189	0.197	
D1	3.15	3.45	0.124	0.136	
E	3.80	4.00	0.150	0.157	
E1	2.26	2.56	0.089	0.101	
е	1.27 BSC		0.050 BSC		
Н	0.19	0.25	0.0075	0.0098	
L	0.41	1.27	0.016	0.050	
θ	0°	8°	0°	8°	

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